TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π -MOS V)

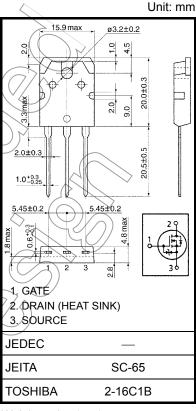
2SK3176

Switching Regulator, DC-DC Converter and Motor Drive Applications

- Low drain-source ON resistance: $R_{DS (ON)} = 38 \text{ m}\Omega \text{ (typ.)}$
- High forward transfer admittance: |Y_{fs}| = 30 S (typ.)
- Low leakage current: I_{DSS} = 100 mA (max) (V_{DS} = 200 V)
- Enhancement-mode: V_{th} = 1.5 to 3.5 V (V_{DS} = 10 V, I_D = 1 mA)

Absolute Maximum Ratings (Ta = 25°C)

| Characteris | tics | Symbol | Rating | Unit |
|------------------------------------|--------------------|-----------------|------------|-------------|
| Drain-source voltage | | V_{DSS} | 200 | (V) |
| Drain-gate voltage (R _G | S = 20 kΩ) | V_{DGR} | 200 | > |
| Gate-source voltage | | V_{GSS} | ±20 | > V |
| Drain current | DC (Note 1) | I _D | 30 | A |
| | Pulse (Note 1) | I _{DP} | 120 | A |
| Drain power dissipation | (Tc = 25°C) | P _D | 150 | W |
| Single pulse avalanche | energy (Note 2) | Eas | 925 | , E |
| Avalanche current | | I _{AR} |)) 30 | Α |
| Repetitive avalanche e | nergy (Note 3) | EAR | 15 〈 | / mJ |
| Channel temperature | | T _{ch} | 150 | /,¢ |
| Storage temperature ra | nge | __\(\tag{stg} | -55 to 450 | Ç |



Weight: 4.6 g (typ.)

- Note 1: Please use devices on condition that the channel temperature is below 150°C.
- Note 2: $V_{DD} = 50 \text{ V}$, $T_{Ch} = 25^{\circ}\text{C}$ (initial), L = 1.66 mH, $R_G = 25 \Omega$, $I_{AR} = 30 \text{ A}$
- Note 3: Repetitive rating: pulse width limited by maximum junction temperature.
- Note 4: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic sensitive device.

Please handle with caution.

Thermal Characteristics

| Characteristics | Symbol | Max | Unit |
|--|------------------------|-------|------|
| Thermal resistance, channel to case | R _{th (ch-c)} | 0.833 | °C/W |
| Thermal resistance, channel to ambient | R _{th (ch-a)} | 50.0 | °C/W |

Electrical Characteristics (Ta = 25°C)

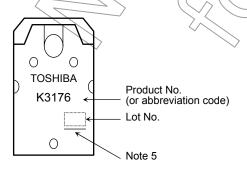
| Charact | eristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---|---------------|----------------------|--|----------------|------|-----|-------|
| Gate leakage currer | nt | I _{GSS} | $V_{GS} = \pm 16 \text{ V}, V_{DS} = 0 \text{ V}$ | _ | _ | ±10 | μА |
| Drain cut-off current | : | I _{DSS} | V _{DS} = 200 V, V _{GS} = 0 V | _ | _ | 100 | μА |
| Drain-source break | down voltage | V (BR) DSS | I _D = 10 mA, V _{GS} = 0 V | 200 | _ | | ٧ |
| Gate threshold volta | ige | V _{th} | V _{DS} = 10 V, I _D = 1 mA | 1.5 | _ | 3.5 | V |
| Drain-source ON res | sistance | R _{DS} (ON) | V _{GS} = 10 V, I _D = 15 A | (F | 38 | 52 | mΩ |
| Forward transfer ad | mittance | Y _{fs} | V _{DS} = 10 V, I _D = 15 A | 15 | 30 | _ | S |
| Input capacitance | | C _{iss} | V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz |)) | 5400 | _ | pF |
| Reverse transfer capacitance | | C _{rss} | V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz | _ | 580 | _ | pF |
| Output capacitance | | Coss | V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz | ⁷ — | 1900 | _ | pF |
| Switching time | Rise time | t _r | VGS 0 V C C C C C C C C C C C C C C C C C C | _ | 15 | 1/ | |
| | Turn-on time | t _{on} | | - (| 55 | > - | |
| | Fall time | t _f | A. A | | 25 |) — | ns ns |
| | Turn-off time | t _{off} | V _{DD} ≈ 100 V Duty ≤ 1%, t _W = 10 μs | | 190 | _ | |
| Total gate charge (gate-source plus ga | ate-drain) | Qg | $V_{DD} \simeq 160 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 30 \text{ A}$ | | 125 | _ | nC |
| Gate-source charge | | Q _{gs} | $V_{DD} \simeq 160 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 30 \text{ A}$ |) — | 80 | _ | nC |
| Gate-drain ("miller") | charge | Q _{gd} | $V_{DD} \simeq 160 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 30 \text{ A}$ | _ | 45 | _ | nC |

Source-Drain Ratings and Characteristics (Ta = 25°C)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit | |
|---|--------------------|--|-----|------|------|------|--|
| Continuous drain reverse current (Note 1) | IDR | | _ | _ | 30 | Α | |
| Pulse drain reverse current (Note 1) | 1 _{DRP} | $(7/\lozenge -$ | _ | _ | 90 | Α | |
| Forward voltage (diode) | √ V _{DSF} | $I_{DR} = 30 \text{ A}, V_{GS} = 0 \text{ V}$ | _ | _ | -2.0 | V | |
| Reverse recovery time | trr | I_{DR} =30 A, V_{GS} = 0 V, I_{DR} /dt = 100 A/ μ s | | 270 | _ | ns | |
| Reverse recovery charge | Q _{rr} | $I_{DR} = 30 \text{ A}, V_{GS} = 0 \text{ V},$ $dI_{DR}/dt = 100 \text{ A}/\mu\text{s}$ | | 3.0 | _ | μС | |

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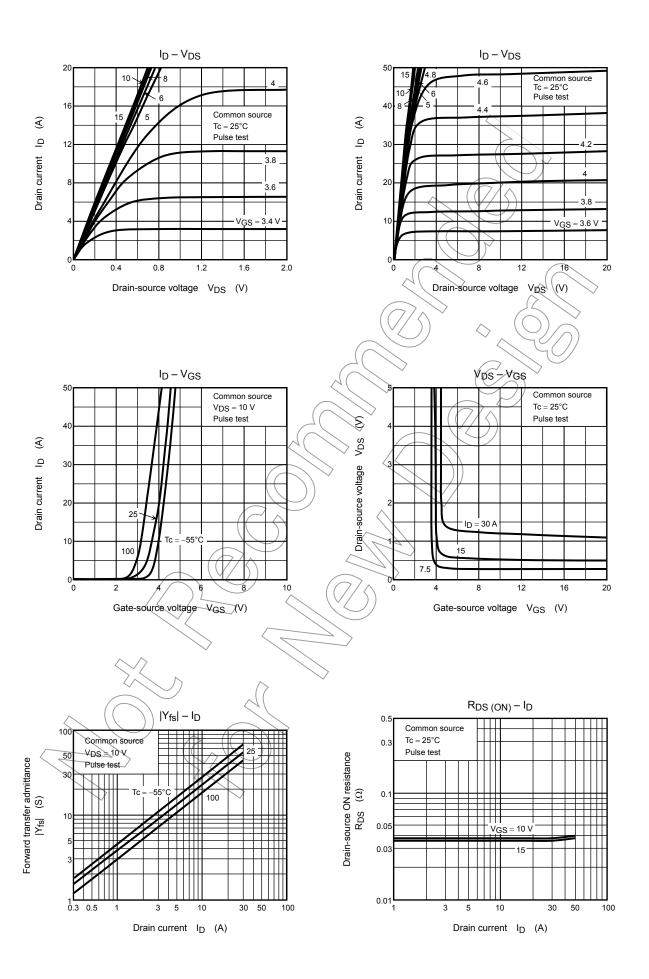


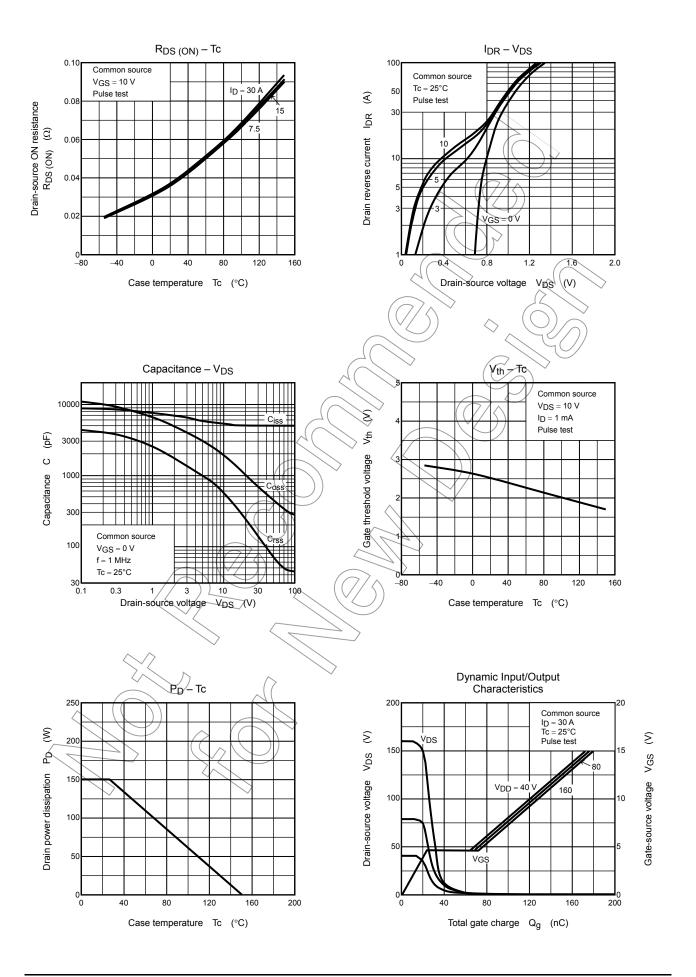
Note 5: A line under a Lot No. identifies the indication of product Labels.

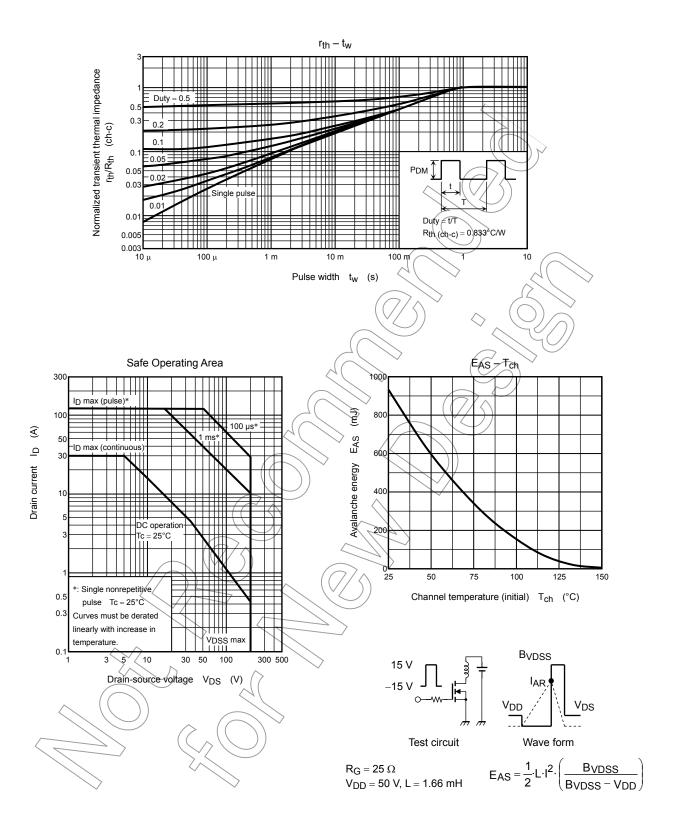
Not underlined: [[Pb]]/INCLUDES > MCV

Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

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